











CSD13306W

SLPS537 - MARCH 2015

CSD13306W 12 V N Channel NexFET™ Power MOSFET

Features

- Ultra Low on Resistance
- Low Q_q and Q_{qd}
- Small Footprint 1 x 1.5 mm
- Low Profile 0.62 mm Height
- Pb Free
- **RoHS Compliant**
- Halogen Free

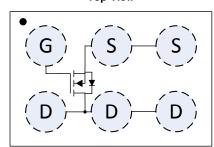
Applications

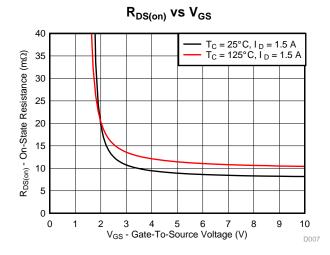
- **Battery Management**
- Load Switch
- **Battery Protection**

Description 3

This 8.8 mΩ, 12 V, N-Channel device is designed to deliver the lowest on resistance and gate charge in a small 1 x 1.5 mm outline with excellent thermal characteristics and an ultra low profile.

Top View





Product Summary

T _A = 25°	С	TYPICAL VA	UNIT			
V_{DS}	Drain-to-Source Voltage	12	V			
Q_g	Sate Charge Total (4.5 V) 8.6					
Q_{gd}	Gate Charge Gate-to-Drain	3.0	nC			
В	Drain-to-Source On-Resistance	V _{GS} = 2.5 V	12.9	mΩ		
R _{DS(on)}	Diam-to-Source On-Resistance	V _{GS} = 4.5 V	8.8	mΩ		
$V_{GS(th)}$	Voltage Threshold	1.0		٧		

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD13306W	3000	7-Inch Reel	1.0 mm × 1.5 mm	Tape and
CSD13306WT	250	7-Inch Reel	Wafer Level Package	Reel

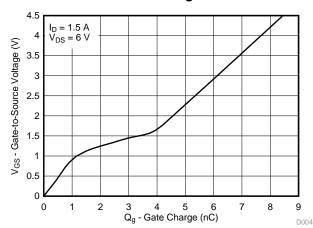
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	12	V
V_{GS}	Gate-to-Source Voltage	±10	V
I_D	Continuous Drain Current ⁽¹⁾	3.5	Α
I _{DM}	Pulsed Drain Current (2)	44	Α
P _D	Power Dissipation ⁽³⁾	1.9	W
T _{stg}	Storage Temperature Range	FF to 150	°C
T _J	Operating Junction Temperature Range	–55 to 150	

- (1) Device Operating at a temperature of 105°C
- (2) Min Cu Typ $R_{\theta JA} = 230^{\circ}$ C/W, Pulse width ≤100 µs, duty cycle
- (3) Max Cu Typ $R_{\theta JA} = 65^{\circ}C/W$

Gate Charge



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4 Revision History

DATE	REVISION	NOTES
March 2015	*	Initial release.



5 Specifications

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5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

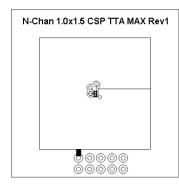
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-Source Voltage	V _{GS} = 0 V, I _D = 250 μA	12			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = 9.6 V			1	μA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = 10 V			100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_{D} = 250 \mu A$	0.7	1.0	1.3	V
D	Designate Course On Booistones	V _{GS} = 2.5 V, I _D = 1.5 A		12.9	15.5	mΩ
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = 4.5 V, I _D = 1.5 A		8.8	10.2	mΩ
g_{fs}	Transconductance	V _{DS} = 1.2 V, I _D =1.5 A		15		S
DYNAM	IC CHARACTERISTICS		•		ļ.	
C _{ISS}	Input Capacitance			1050	1370	pF
Coss	Output Capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 6 \text{ V}, f = 1 \text{ MHz}$		324	421	pF
C _{RSS}	Reverse Transfer Capacitance			226	294	pF
R _g				4.2	8.4	Ω
Qg	Gate Charge Total (4.5V)			8.6	11.2	nC
Q _{gd}	Gate Charge Gate-to-Drain	V 0VI 45A		3.0		nC
Q _{gs}	Gate Charge Gate-to-Source	$V_{DS} = 6 \text{ V}, I_{D} = 1.5 \text{ A}$		1.1		nC
Q _{g(th)}	Gate Charge at Vth			1.2		nC
Q _{OSS}	Output Charge	V _{DS} = 6 V, V _{GS} = 0 V		3.3		nC
t _{d(on)}	Turn On Delay Time			7		ns
t _r	Rise Time	V _{DS} = 6 V, V _{GS} = 4.5 V, I _D = 1.5 A		11		ns
t _{d(off)}	Turn Off Delay Time	$R_G = 4 \Omega$		20		ns
t_f	Fall Time			8		ns
DIODE (CHARACTERISTICS					
V _{SD}	Diode Forward Voltage	I _S = 1.5 A, V _{GS} = 0 V		0.7	1.0	V
Q _{rr}	Reverse Recovery Charge	V 0 V 1 4 5 A 3 V 1 000 A / v 2		14.8		nC
t _{rr}	Reverse Recovery Time	V_{DS} = 6 V, I_F = 1.5 A, di/dt = 200 A/ μ s		23		ns

5.2 Thermal Information

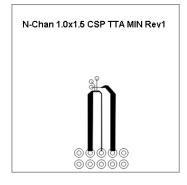
T_A = 25°C unless otherwise stated

	THERMAL METRIC	MIN	TYP	MAX	UNIT
_	Junction-to-Ambient Thermal Resistance (1)		230		۸۸.
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance (2)		65		°C/W

- (1) Device mounted on FR4 material with minimum Cu mounting area
 (2) Device mounted on FR4 material with 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu.



Typ $R_{\theta JA} = 65^{\circ}C/W$ when mounted on 1 inch² of 2 oz. Cu.

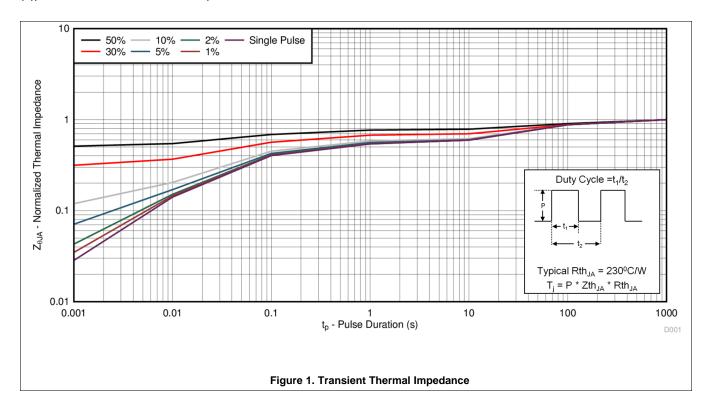


Typ $R_{\theta JA} = 230$ °C/W when mounted on minimum pad area of 2 oz. Cu.



5.3 Typical MOSFET Characteristics

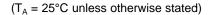
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

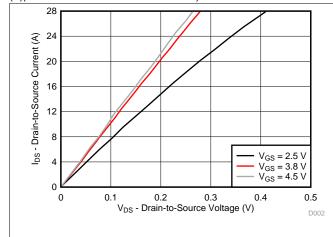




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Typical MOSFET Characteristics (continued)





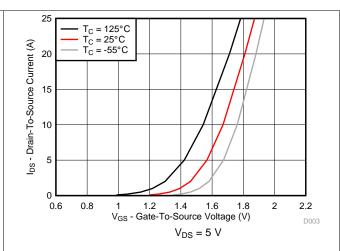
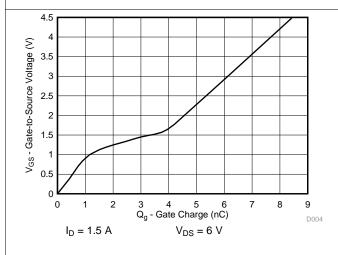


Figure 2. Saturation Characteristics





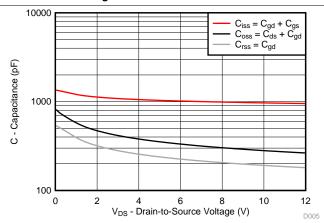
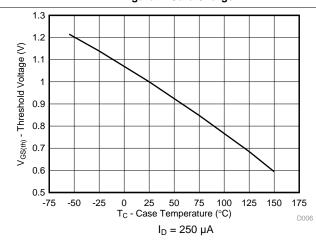


Figure 4. Gate Charge



24 $T_C = 25^{\circ}C$, $I_D = 1.5$ A $T_C = 125^{\circ}C$, $I_D = 1.5$ A R_{DS(on)} - On-State Resistance (mΩ) 21 15 12 9 3 0 3 4 5 0 6 10 V_{GS} - Gate-To-Source Voltage (V)

Figure 5. Capacitance

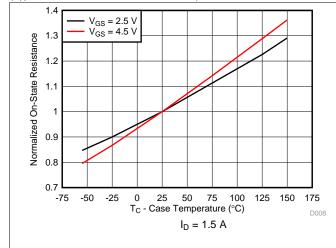
Figure 6. Threshold Voltage vs Temperature

Figure 7. On-State Resistance vs Gate-to-Source Voltage

TEXAS INSTRUMENTS

Typical MOSFET Characteristics (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



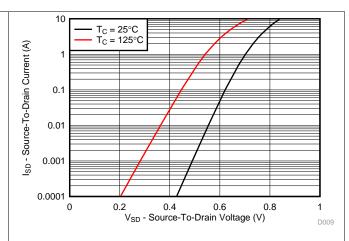


Figure 8. Normalized On-State Resistance vs Temperature

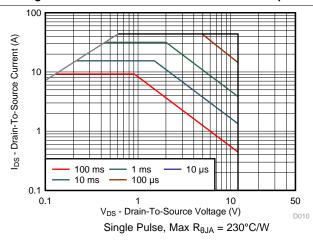


Figure 9. Typical Diode Forward Voltage

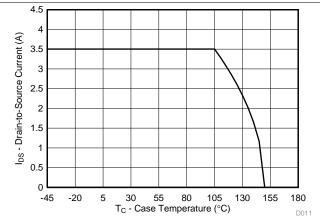


Figure 10. Maximum Safe Operating Area

Figure 11. Maximum Drain Current vs Temperature



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6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

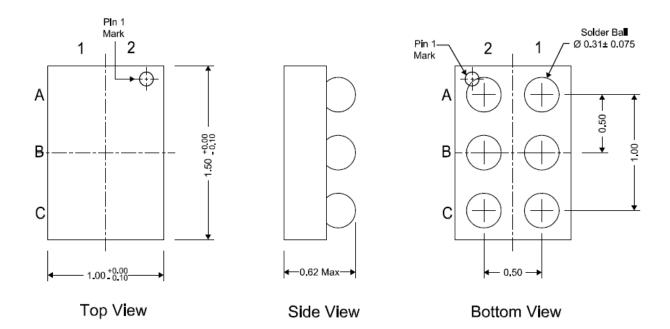
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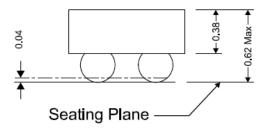
TEXAS INSTRUMENTS

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 CSD13306W Package Dimensions





Front View

NOTE: All dimensions are in mm (unless otherwise specified)

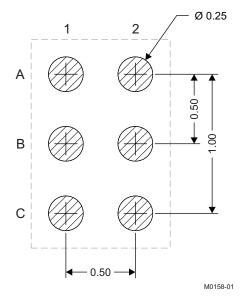
Pinout

POSITION	DESIGNATION
C2, B2	Source
A2	Gate
A1, B1, C1	Drain



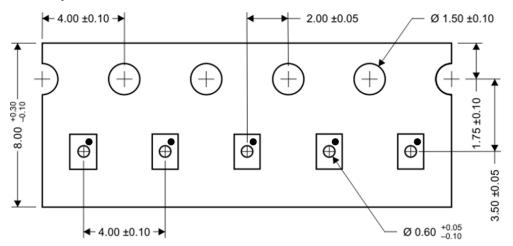
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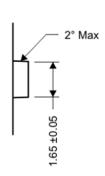
Land Pattern Recommendation

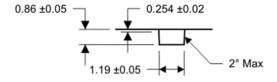


NOTE: All dimensions are in mm (unless otherwise specified)

7.2 Tape and Reel Information







M0159-01

NOTE: All dimensions are in mm (unless otherwise specified)



PACKAGE OPTION ADDENDUM

1-Dec-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD13306W	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		13306	Samples
CSD13306WT	ACTIVE	DSBGA	YZC	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		13306	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

1-Dec-2015

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